## NSN 5961-01-384-1796

**Fiig:** A110a0

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View Online at https://aerobasegroup.com/nsn/5961-01-384-1796 **Inclosure Material:** Plastic **Overall Length:** Between 5.80 millimeters and 6.20 millimeters **Terminal Length:** Between 0.0395 millimeters and 0.0435 millimeters **Overall Height:** Between 1.35 millimeters and 1.75 millimeters **Overall Width:** Between 4.80 millimeters and 5.00 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: So-8 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open all transistor and 15.0 collector to emitter voltage/static/base open all transistor and 2.5 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.67 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 8 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No